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[Vishay Semiconductor/Diodes Division](#)
[VESD15A1-HD1-G4-08](#)

For any questions, you can email us directly:

sales@integrated-circuit.com

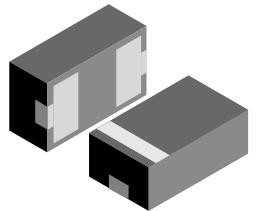
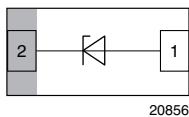


www.vishay.com

VESD15A1-HD1

Vishay Semiconductors

ESD-Protection Diode in LLP1006-2L



20856

20855

FEATURES

- Ultra compact LLP1006-2L package
- Low package height < 0.4 mm
- 1-line ESD-protection
- Low leakage current < 0.01 μ A
- Low load capacitance $C_D = 45$ pF ($V_R = 0$ V; $f = 1$ MHz)
- ESD-protection acc. IEC 61000-4-2
 ± 30 kV contact discharge
 ± 30 kV air discharge
- High surge current acc. IEC61000-4-5 $I_{PP} > 6$ A
- Soldering can be checked by standard vision inspection.
 No X-ray necessary
- Pin plating NiPdAu (e4) no whisker growth
- e4 - precious metal (e.g. Ag, Au, NiPd, NiPdAu) (no Sn)
- Material categorization: for definitions of compliance
 please see www.vishay.com/doc?99912



e4

RoHS
 COMPLIANT
 HALOGEN
 FREE
GREEN
 (S-2008)

MARKING (example only)



Bar = cathode marking

X = date code

Y = type code (see table below)

ORDERING INFORMATION

| DEVICE NAME | ORDERING CODE | TAPED UNITS PER REEL (8 mm TAPE on 7" REEL) | MINIMUM ORDER QUANTITY |
|--------------|--------------------|------------------------------------------------|------------------------|
| VESD15A1-HD1 | VESD15A1-HD1-G4-08 | 8000 | 8000 |

PACKAGE DATA

| DEVICE NAME | PACKAGE NAME | TYPE CODE | WEIGHT | MOLDING COMPOUND FLAMMABILITY RATING | MOISTURE SENSITIVITY LEVEL | SOLDERING CONDITIONS |
|--------------|--------------|-----------|---------|--------------------------------------|--------------------------------------|---------------------------------|
| VESD15A1-HD1 | LLP1006-2L | W | 0.72 mg | UL 94 V-0 | MSL level 1 (according J-STD-020) | Peak temperature max. 260 °C |

ABSOLUTE MAXIMUM RATINGS VESD15A1-HD1

| PARAMETER | TEST CONDITIONS | SYMBOL | VALUE | UNIT |
|-----------------------|-------------------------------------------------------|-----------|-------------|------|
| Peak pulse current | Acc. IEC 61000-4-5; $t_P = 8/20$ μ s; single shot | I_{PPM} | 6 | A |
| Peak pulse power | Acc. IEC 61000-4-5; $t_P = 8/20$ μ s; single shot | P_{PP} | 150 | W |
| ESD immunity | Contact discharge acc. IEC 61000-4-2; 10 pulses | V_{ESD} | ± 30 | kV |
| | Air discharge acc. IEC 61000-4-2; 10 pulses | | ± 30 | kV |
| Operating temperature | Junction temperature | T_J | -40 to +125 | °C |
| Storage temperature | | T_{stg} | -55 to +150 | °C |

PATENT(S): www.vishay.com/patents

This Vishay product is protected by one or more United States and International patents.

ELECTRICAL CHARACTERISTICS VESD15A1-HD1

($T_{amb} = 25^\circ\text{C}$, unless otherwise specified)

| PARAMETER | TEST CONDITIONS/REMARKS | SYMBOL | MIN. | TYP. | MAX. | UNIT |
|---------------------------|-----------------------------------------------------------------------------------|---------------|------|--------|------|---------------|
| Protection paths | Number of line which can be protected | $N_{channel}$ | - | - | 1 | lines |
| Reverse stand-off voltage | Max. reverse working voltage | V_{RWM} | - | - | 15 | V |
| Reverse voltage | at $I_R = 0.1 \mu\text{A}$ | V_R | 15 | - | - | V |
| Reverse current | at $V_R = 15 \text{ V}$ | I_R | - | < 0.01 | 0.1 | μA |
| Reverse breakdown voltage | at $I_R = 1 \text{ mA}$ | V_{BR} | 15.5 | 16 | 17 | V |
| Reverse clamping voltage | at $I_{PP} = 1 \text{ A}$ | V_C | - | 18 | 20 | V |
| | at $I_{PP} = I_{PPM} = 6 \text{ A}$ | V_C | - | 24 | 27 | V |
| Forward clamping voltage | at $I_{PP} = 0.2 \text{ A}$ | V_F | - | 0.85 | 1.2 | V |
| | at $I_{PP} = 1 \text{ A}$ | V_F | - | 1.1 | 1.3 | V |
| | at $I_{PP} = I_{PPM} = 6 \text{ A}$ | V_F | - | 2.0 | 2.5 | V |
| Capacitance | at $V_R = 0 \text{ V}; f = 1 \text{ MHz}$ | C_D | - | 45 | 50 | pF |
| | at $V_R = 7.5 \text{ V}; f = 1 \text{ MHz}$ | C_D | - | 18 | - | pF |
| Clamping voltage | Transmission line pulse (TLP), $t_p = 100 \text{ ns}$ $I_{TLP} = 8 \text{ A}$ | V_{C-TLP} | - | 19 | - | V |
| | Transmission line pulse (TLP), $t_p = 100 \text{ ns}$ $I_{TLP} = 16 \text{ A}$ | V_{C-TLP} | - | 20.5 | - | V |
| Dynamic resistance | Transmission line pulse (TLP), $t_p = 100 \text{ ns}$ | R_{DYN} | - | 0.27 | - | Ω |

BiAs-MODE (bidirectional asymmetrical protection mode)

With the VESD15A1-HD1 one signal- or data-lines (L1) can be protected against voltage transients. With pin 1 connected to ground and pin 2 connected to a signal- or data-line which has to be protected. As long as the voltage level on the data- or signal-line is between 0 V (ground level) and the specified maximum reverse working voltage (V_{RWM}) the protection diode between data line and ground offers a high isolation to the ground line. The protection device behaves like an open switch.

As soon as any positive transient voltage signal exceeds the break through voltage level of the protection diode, the diode becomes conductive and shorts the transient current to ground. Now the protection device behaves like a closed switch. The clamping voltage (V_C) is defined by the breakthrough voltage (V_{BR}) level plus the voltage drop at the series impedance (resistance and inductance) of the protection device.

Any negative transient signal will be clamped accordingly. The negative transient current is flowing in the forward direction of the protection diode. The low forward voltage (V_F) clamps the negative transient close to the ground level.

Due to the different clamping levels in forward and reverse direction the VESD15A1-HD1 clamping behavior is bidirectional and asymmetrical (BiAs).





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VESD15A1-HD1

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TYPICAL CHARACTERISTICS ($T_{amb} = 25^{\circ}\text{C}$, unless otherwise specified)

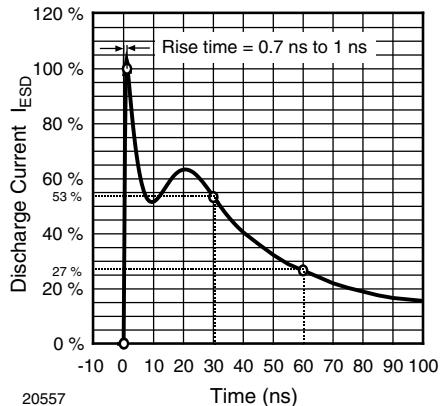


Fig. 1 - ESD Discharge Current Wave Form
acc. IEC 61000-4-2 (330 Ω /150 pF)

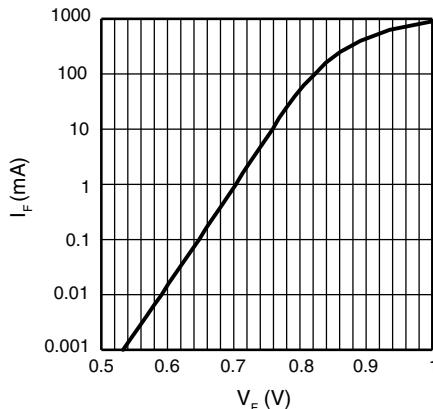


Fig. 4 - Typical Forward Current I_F vs. Forward Voltage V_F

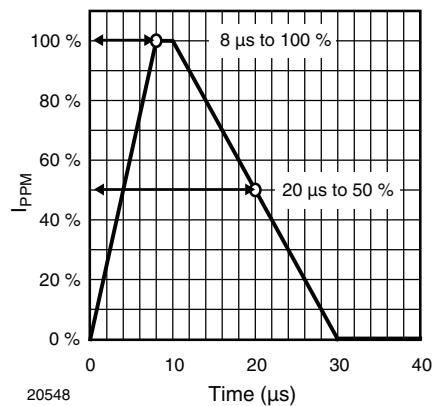


Fig. 2 - 8/20 μ s Peak Pulse Current Wave Form
acc. IEC 61000-4-5

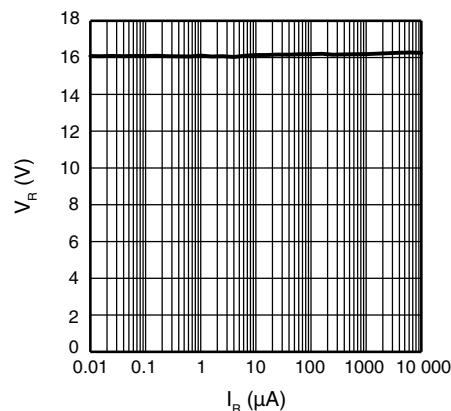


Fig. 5 - Typical Reverse Voltage V_R vs.
Reverse Current I_R

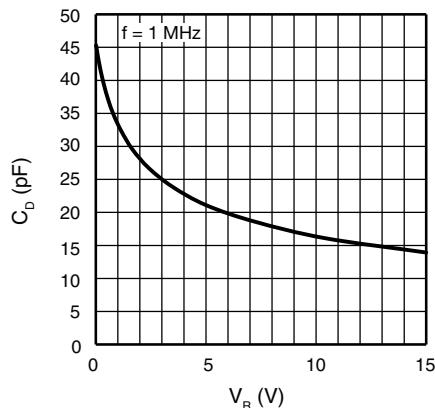


Fig. 3 - Typical Capacitance C_D vs. Reverse Voltage V_R

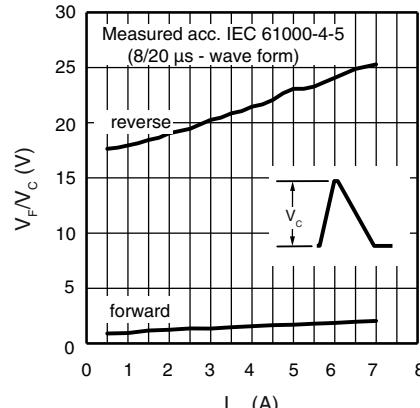


Fig. 6 - Typical Clamping Voltage vs.
Peak Pulse Current I_{PP}



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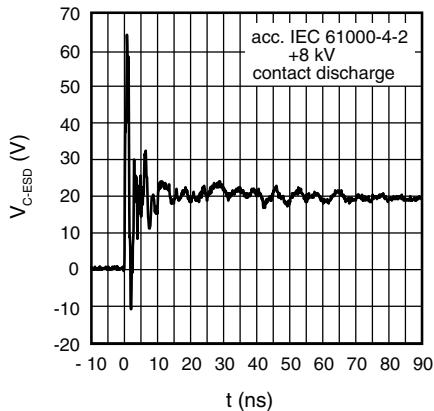


Fig. 7 - Typical Clamping Performance at +8 kV
Contact Discharge (acc. IEC 61000-4-2)

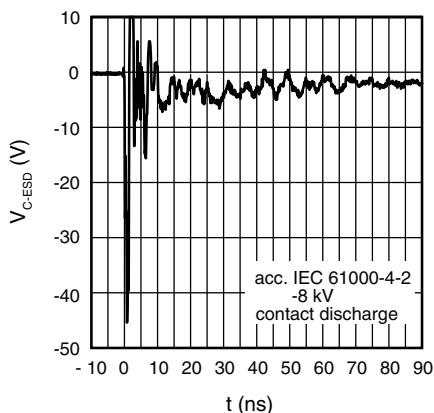


Fig. 8 - Typical Clamping Performance at -8 kV
Contact Discharge (acc. IEC 61000-4-2)

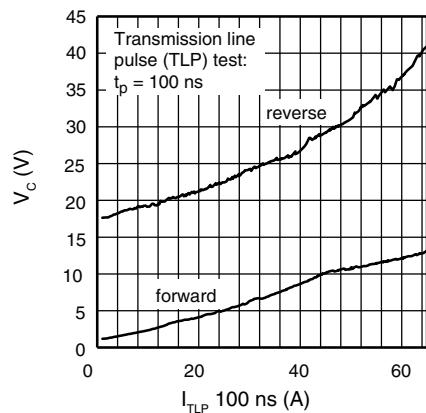
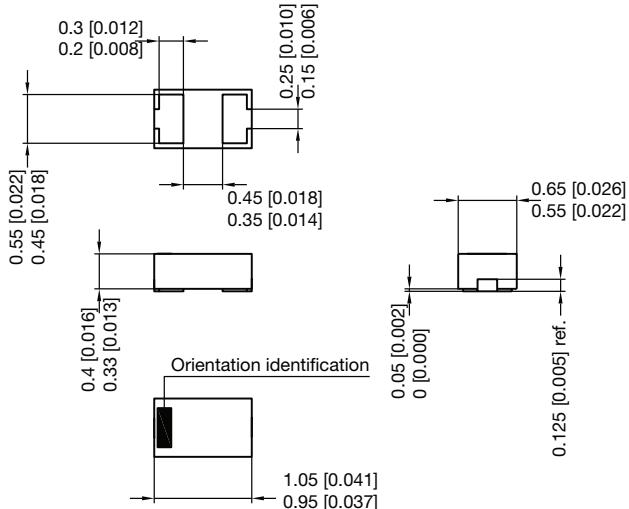
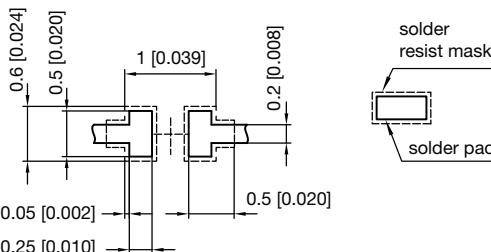


Fig. 9 - Typical Peak Clamping Voltage vs. TLP current
(TLP = transmission line pulse; $t_p = 100$ ns)

PACKAGE DIMENSIONS in millimeters (inches): **LLP1006-2L**

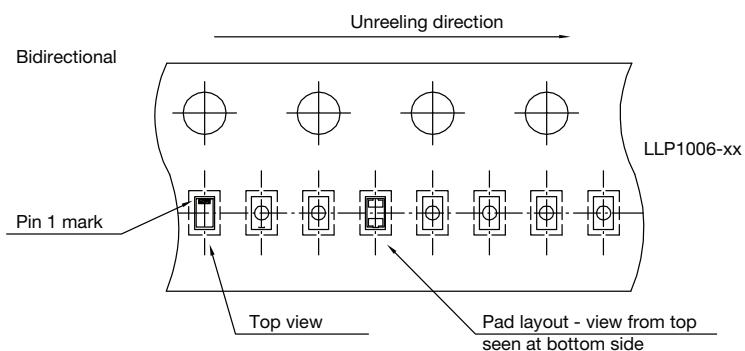


Foot print recommendation:



Pad Design Patented:
(P)US 9,018,537 B2)

Document no.: S8-V-3906.04-005 (4)
Rev. 7 - Date: 11.May 2016
20812





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